



**THE DATASHEET OF  
MMUN2233LT1**



# MMUN2211LT1 Series

Preferred Devices

## Bias Resistor Transistor

### NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SOT-23 package which is designed for low power surface mount applications.

#### Features

- Simplifies Circuit Design
- Reduces Board Space and Component Count
- Pb-Free Packages are Available

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB0</sub>	50	Vdc
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector Current	I <sub>C</sub>	100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	246 (Note 1) 400 (Note 2) 1.5 (Note 1) 2.0 (Note 2)	mW °C/W
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub>	508 (Note 1) 311 (Note 2)	°C/W
Thermal Resistance, Junction-to-Lead	R <sub>θJL</sub>	174 (Note 1) 208 (Note 2)	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

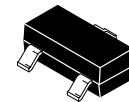
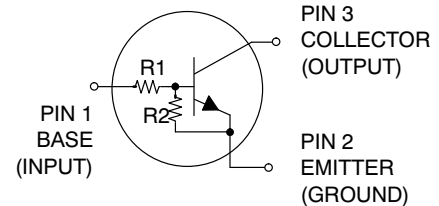
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ minimum pad
2. FR-4 @ 1.0 x 1.0 inch pad



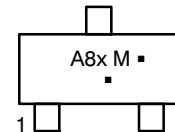
ON Semiconductor®

<http://onsemi.com>



SOT-23  
CASE 318  
STYLE 6

#### MARKING DIAGRAM



A8x = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package  
(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 16 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

# MMUN2211LT1 Series

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector-Base Cutoff Current (V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-	100	nAdc
Collector-Emitter Cutoff Current (V <sub>CE</sub> = 50 V, I <sub>B</sub> = 0)	I <sub>CEO</sub>	-	-	500	nAdc
Emitter-Base Cutoff Current (V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0)	I <sub>EBO</sub>	-	-	0.5	mAdc
MMUN2211LT1, G		-	-	0.2	
MMUN2212LT1, G		-	-	0.1	
MMUN2213LT1, G		-	-	0.2	
MMUN2214LT1, G		-	-	0.9	
MMUN2215LT1, G		-	-	1.9	
MMUN2216LT1, G		-	-	4.3	
MMUN2230LT1, G		-	-	2.3	
MMUN2231LT1, G		-	-	1.5	
MMUN2232LT1, G		-	-	0.18	
MMUN2233LT1, G		-	-	0.13	
MMUN2234LT1, G		-	-	4.0	
MMUN2238LT1, G		-	-	0.1	
MMUN2241LT1, G		-	-		
Collector-Base Breakdown Voltage (I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 3), (I <sub>C</sub> = 2.0 mA, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	50	-	-	Vdc

## ON CHARACTERISTICS (Note 3)

DC Current Gain (V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5.0 mA)	MMUN2211LT1, G MMUN2212LT1, G MMUN2213LT1, G MMUN2214LT1, G MMUN2215LT1, G MMUN2216LT1, G MMUN2230LT1, G MMUN2231LT1, G MMUN2232LT1, G MMUN2233LT1, G MMUN2234LT1, G MMUN2238LT1, G MMUN2241LT1, G	h <sub>FE</sub>	35 60 80 80 160 160 3.0 8.0 15 80 80 160 160	60 100 140 140 350 350 5.0 15 30 200 150 350 350	- - - - - - - - - - - - -	
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.3 mA)	MMUN2211LT1, G MMUN2212LT1, G MMUN2213LT1, G MMUN2214LT1, G MMUN2233LT1, G MMUN2234LT1, G	V <sub>CE(sat)</sub>	- - - - - -	- - - - - -	0.25 0.25 0.25 0.25 0.25 0.25	Vdc
(I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1 mA)	MMUN2215LT1, G MMUN2216LT1, G MMUN2232LT1, G MMUN2238LT1, G		- - - -	- - - -	0.25 0.25 0.25 0.25	
(I <sub>C</sub> = 10 mA, I <sub>B</sub> = 5 mA)	MMUN2230LT1, G MMUN2231LT1, G MMUN2241LT1, G		- - -	- - -	0.25 0.25 0.25	

3. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%.

# MMUN2211LT1 Series

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit		
<b>ON CHARACTERISTICS</b> (Note 4)							
Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 2.5 V, R <sub>L</sub> = 1.0 kΩ)	V <sub>OL</sub>	-	-	0.2	Vdc		
MMUN2211LT1, G							
MMUN2212LT1, G							
MMUN2214LT1, G							
MMUN2215LT1, G							
MMUN2216LT1, G							
MMUN2230LT1, G							
MMUN2231LT1, G							
MMUN2232LT1, G							
MMUN2233LT1, G							
MMUN2234LT1, G							
MMUN2238LT1, G							
(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 3.5 V, R <sub>L</sub> = 1.0 kΩ)							
(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 5.0 V, R <sub>L</sub> = 1.0 kΩ)							
MMUN2213LT1, G							
MMUN2241LT1, G							
Output Voltage (off) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.5 V, R <sub>L</sub> = 1.0 kΩ)	V <sub>OH</sub>	4.9	-	-	Vdc		
MMUN2211LT1, G							
MMUN2212LT1, G							
MMUN2213LT1, G							
MMUN2214LT1, G							
MMUN2233LT1, G							
(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.05 V, R <sub>L</sub> = 1.0 kΩ)							
MMUN2230LT1, G							
MMUN2234LT1, G							
(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.25 V, R <sub>L</sub> = 1.0 kΩ)							
MMUN2215LT1, G							
MMUN2216LT1, G							
MMUN2231LT1, G							
MMUN2232LT1, G							
MMUN2238LT1, G							
MMUN2241LT1, G							
Input Resistor		R1	7.0	10		13	kΩ
MMUN2211LT1, G							
MMUN2212LT1, G							
MMUN2213LT1, G							
MMUN2214LT1, G							
MMUN2215LT1, G							
MMUN2216LT1, G							
MMUN2230LT1, G							
MMUN2231LT1, G							
MMUN2232LT1, G							
MMUN2233LT1, G							
MMUN2234LT1, G							
MMUN2238LT1, G							
MMUN2241LT1, G							
Resistor Ratio	R1/R2		0.8	1.0	1.2		
MMUN2211LT1, G							
MMUN2212LT1, G							
MMUN2213LT1, G							
MMUN2214LT1, G							
MMUN2215LT1, G							
MMUN2216LT1, G							
MMUN2230LT1, G							
MMUN2231LT1, G							
MMUN2232LT1, G							
MMUN2233LT1, G							
MMUN2234LT1, G							
MMUN2238LT1, G							
MMUN2241LT1, G							

4. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%.

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MMUN2211LT1

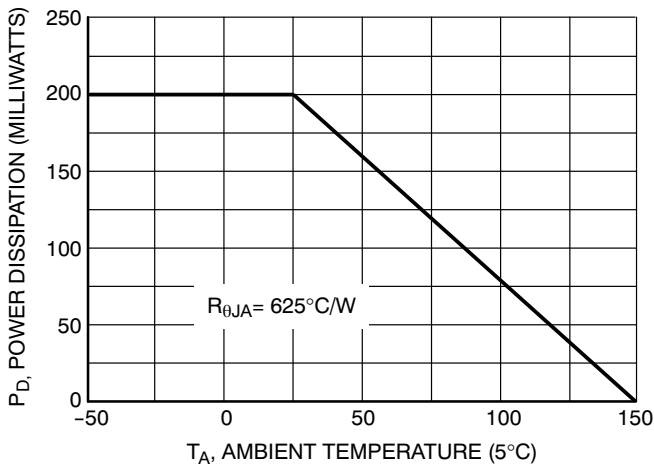


Figure 1. Derating Curve

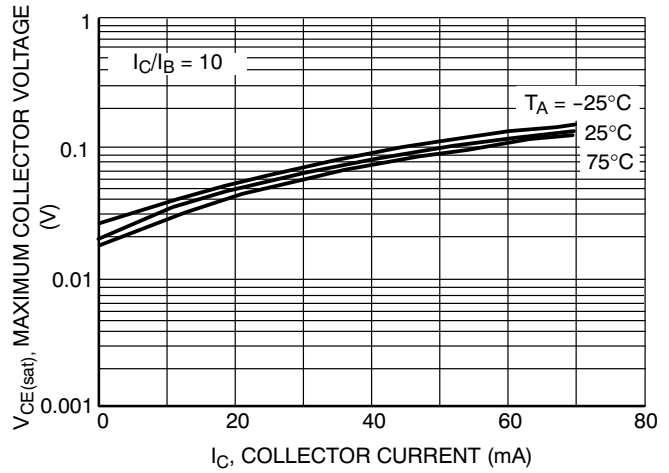


Figure 2. V<sub>CE(sat)</sub> vs. I<sub>C</sub>

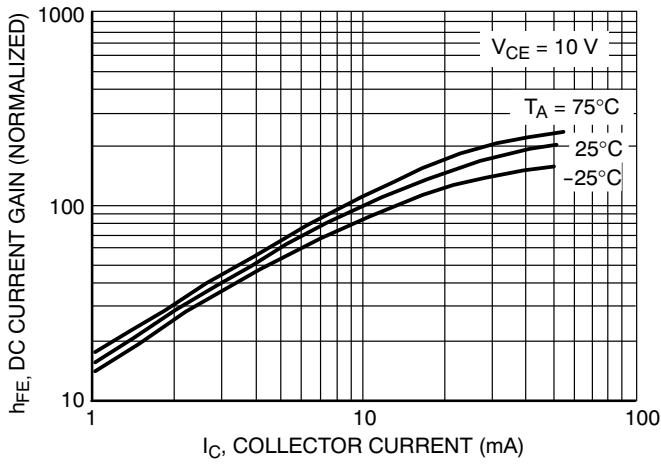


Figure 3. DC Current Gain

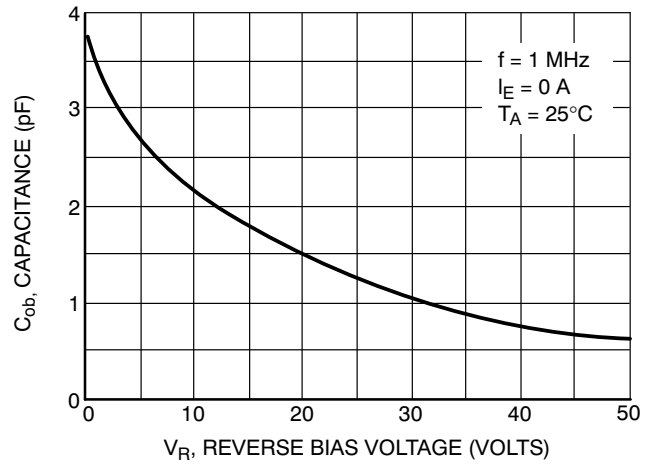


Figure 4. Output Capacitance

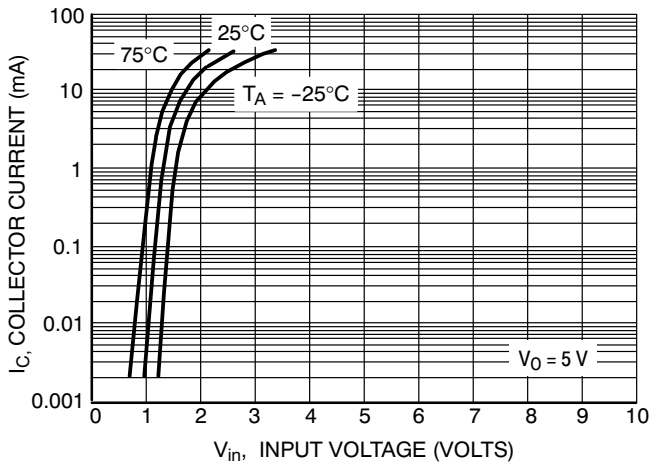


Figure 5. Output Current vs. Input Voltage

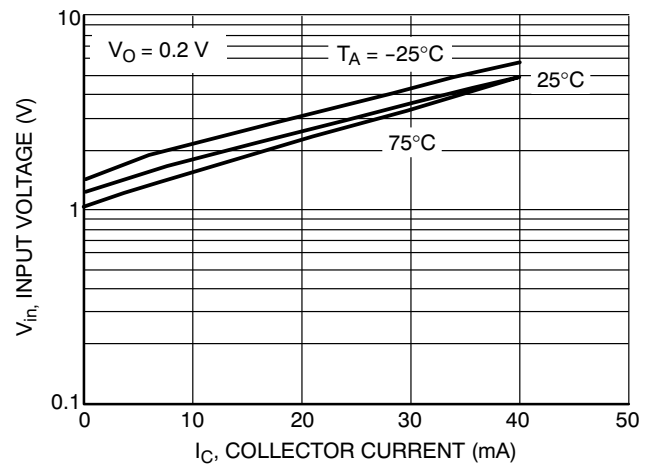


Figure 6. Input Voltage vs. Output Current

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MMUN2212LT1

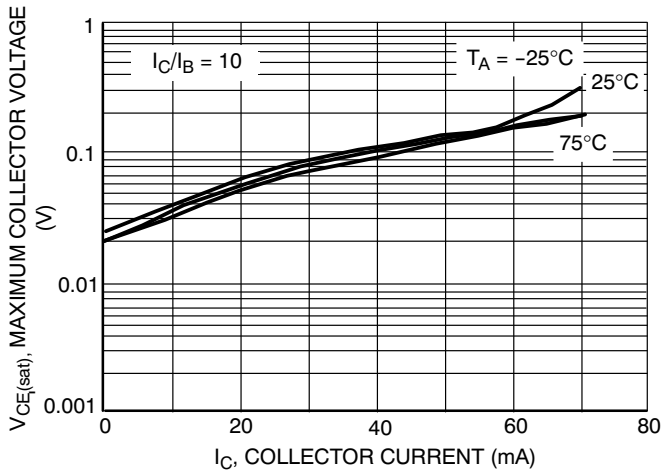


Figure 7.  $V_{CE(sat)}$  vs.  $I_C$

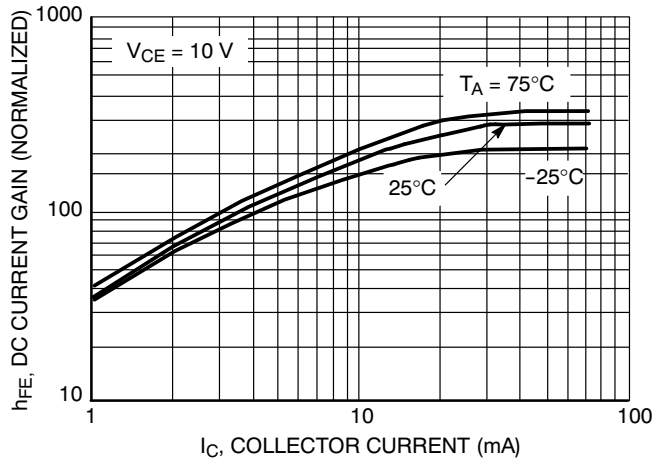


Figure 8. DC Current Gain

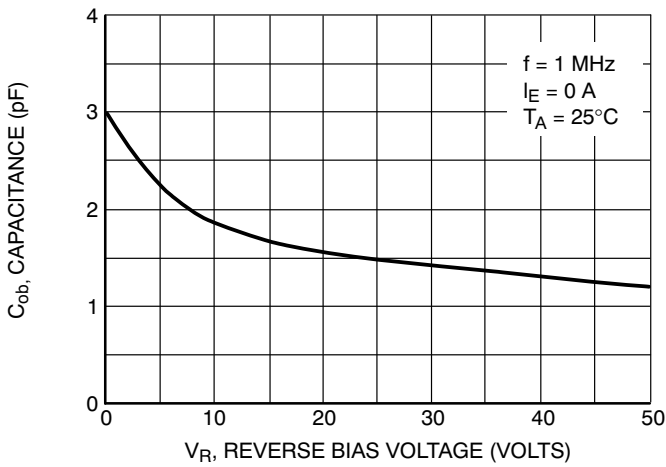


Figure 9. Output Capacitance

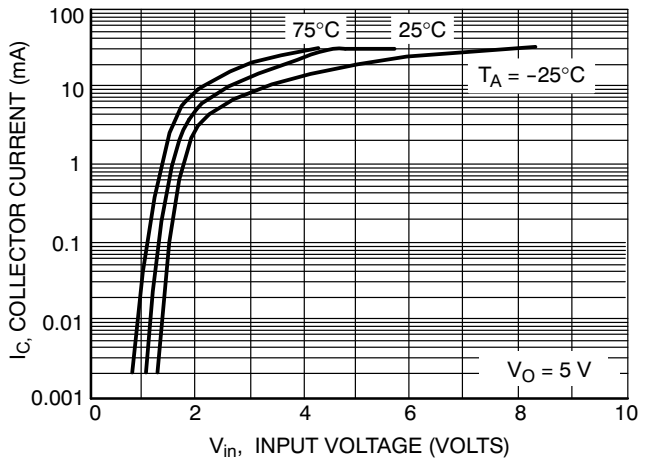


Figure 10. Output Current vs. Input Voltage

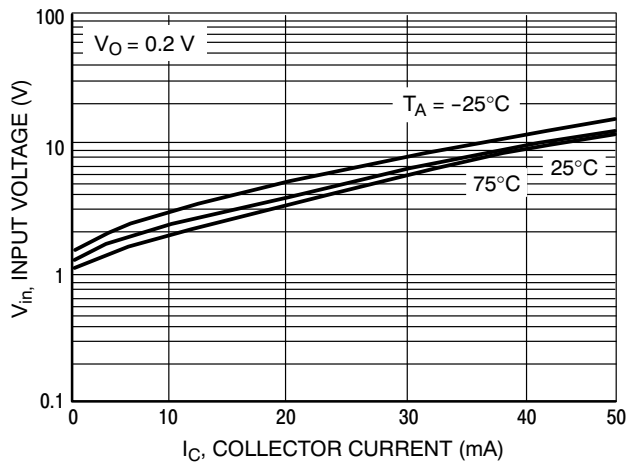


Figure 11. Input Voltage vs. Output Current

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MMUN2213LT1

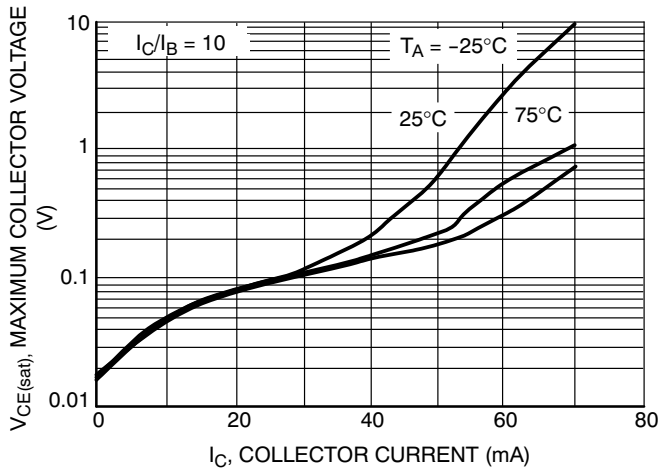


Figure 12.  $V_{CE(sat)}$  vs.  $I_C$

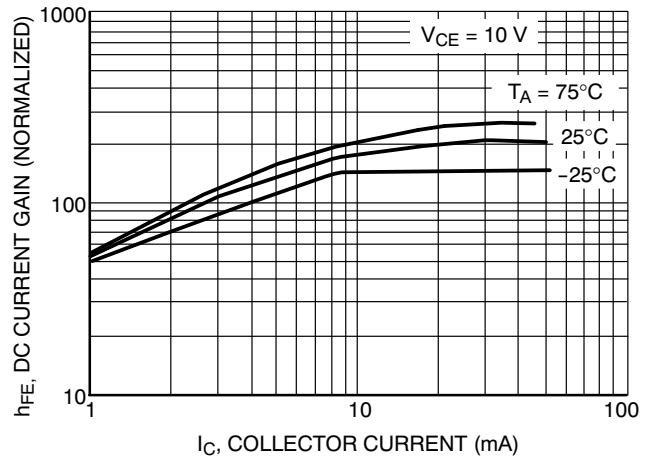


Figure 13. DC Current Gain

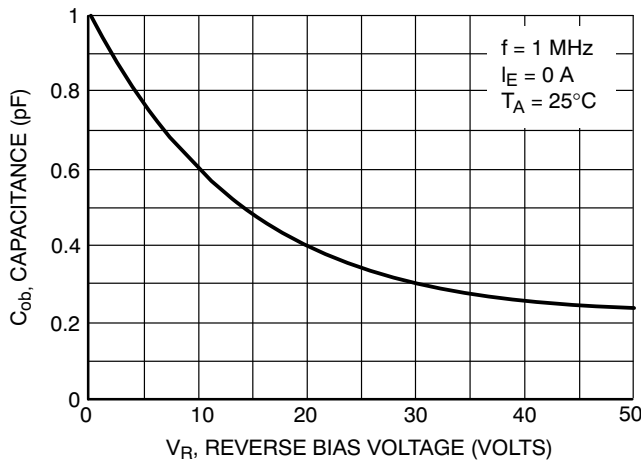


Figure 14. Output Capacitance

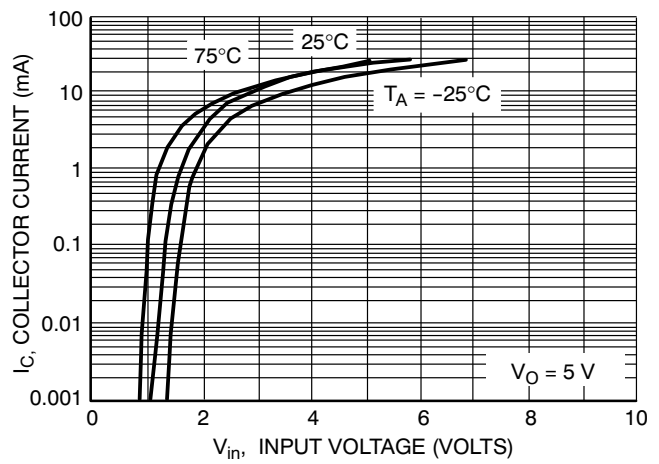


Figure 15. Output Current vs. Input Voltage

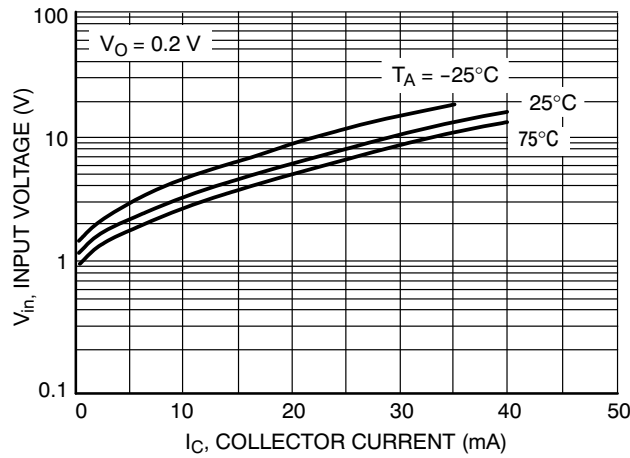


Figure 16. Input Voltage vs. Output Current

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MMUN2214LT1

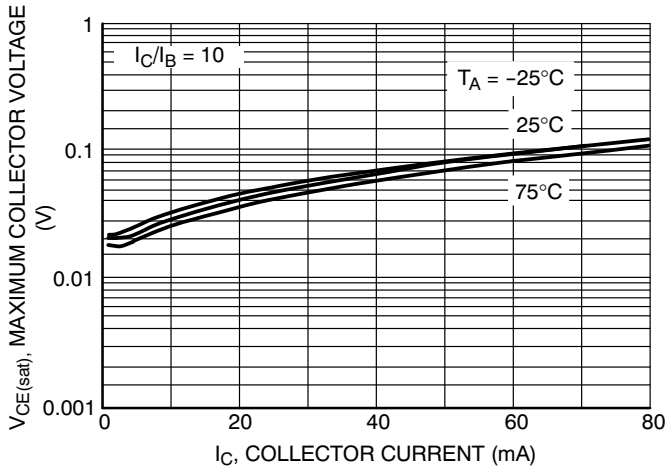


Figure 17.  $V_{CE(sat)}$  vs.  $I_C$

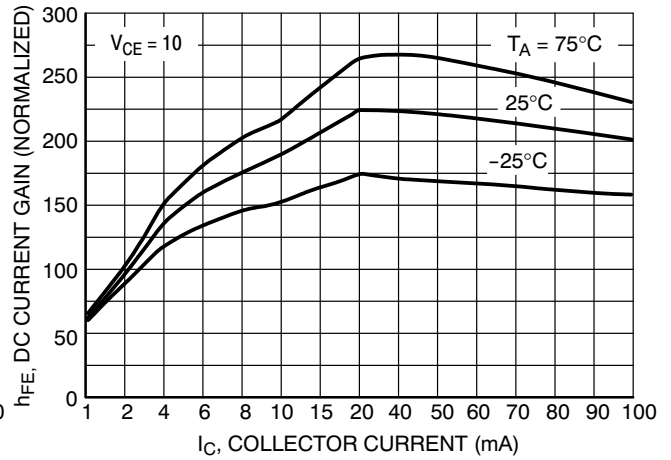


Figure 18. DC Current Gain

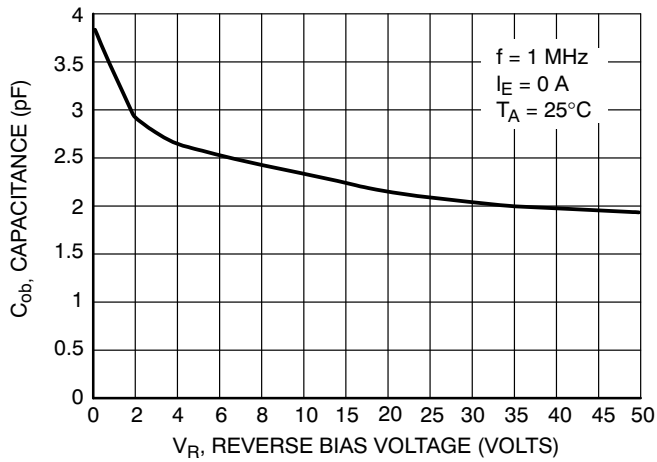


Figure 19. Output Capacitance

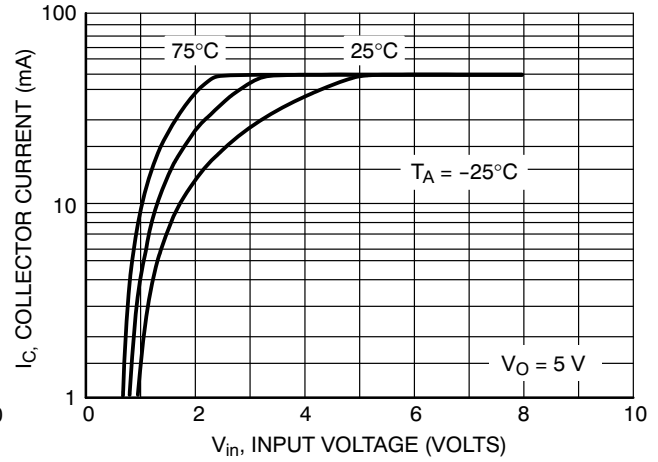


Figure 20. Output Current vs. Input Voltage

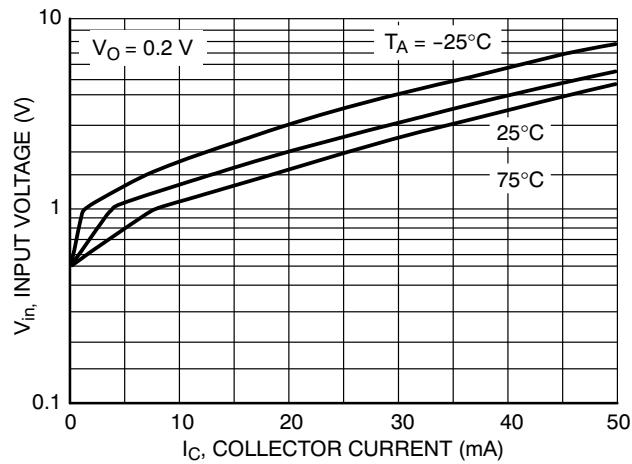


Figure 21. Input Voltage vs. Output Current

TYPICAL ELECTRICAL CHARACTERISTICS - MMUN2215LT1

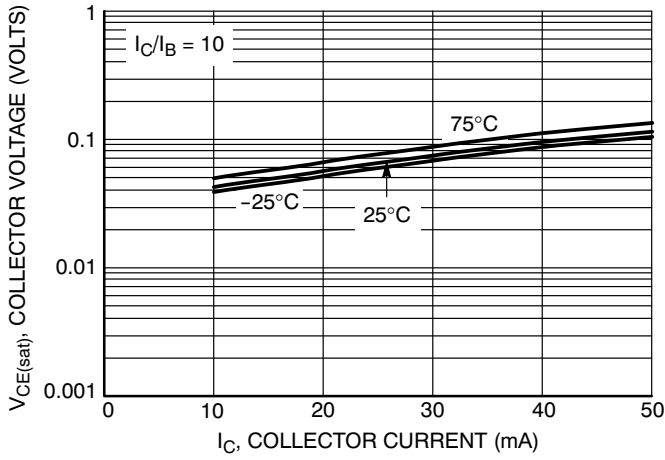


Figure 22.  $V_{CE(sat)}$  versus  $I_C$

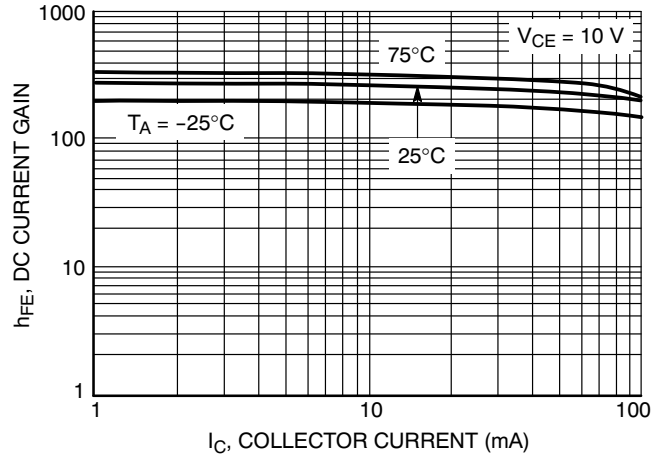


Figure 23. DC Current Gain

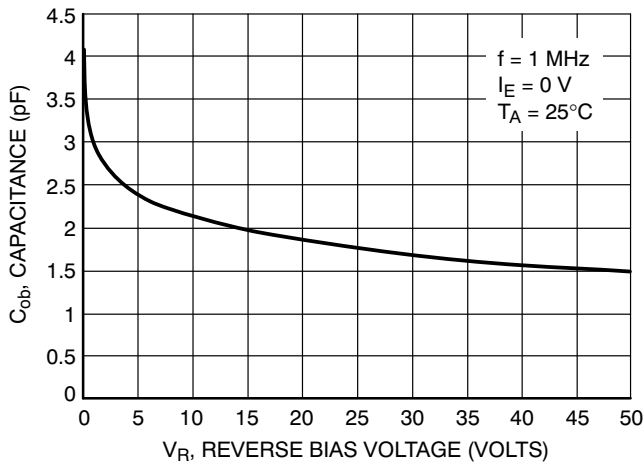


Figure 24. Output Capacitance

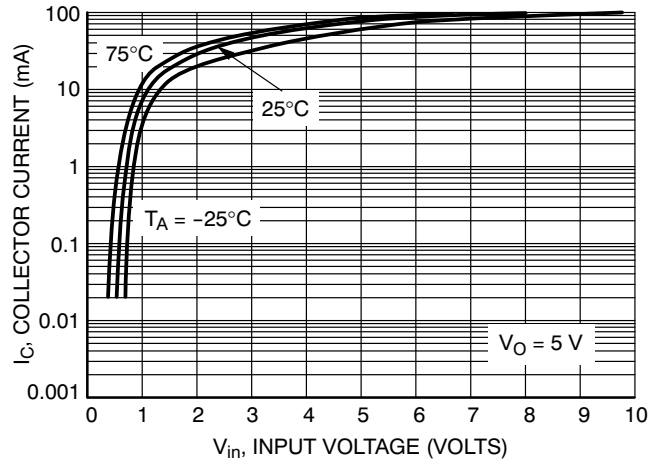


Figure 25. Output Current versus Input Voltage

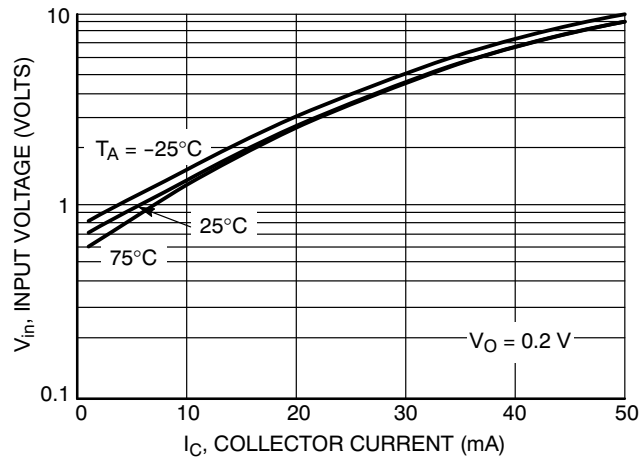
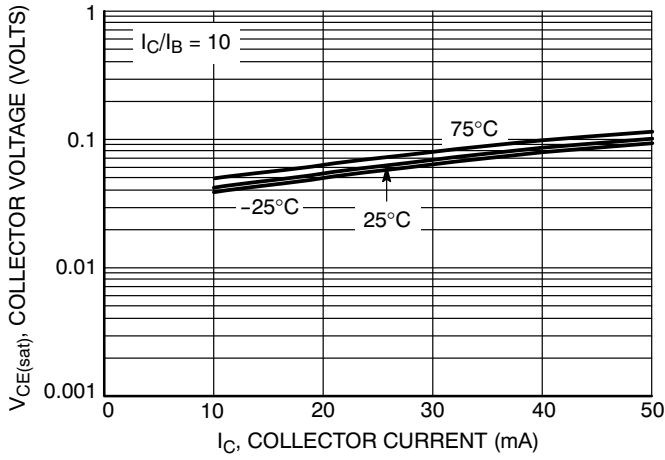


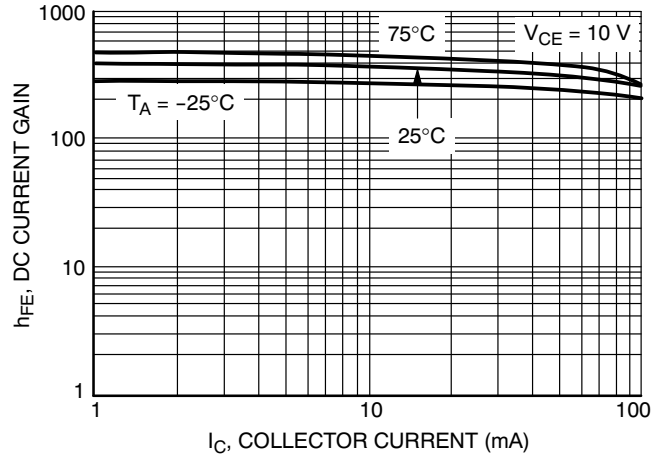
Figure 26. Input Voltage versus Output Current

# MMUN2211LT1 Series

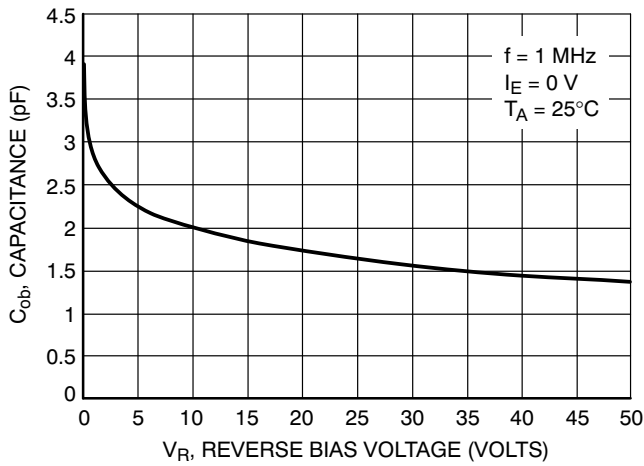
## TYPICAL ELECTRICAL CHARACTERISTICS — MMUN2216LT1



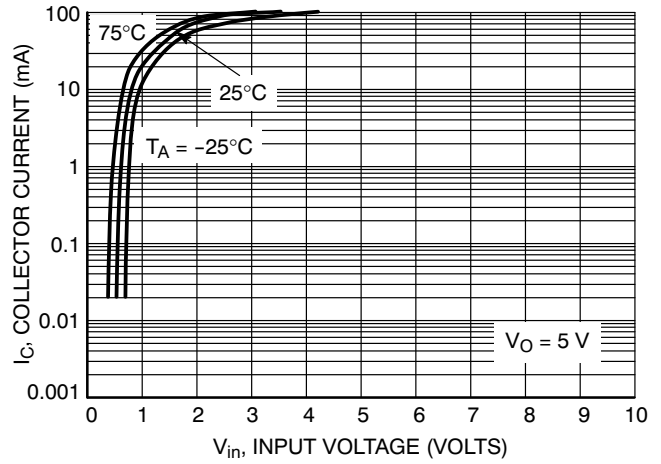
**Figure 27.  $V_{CE(sat)}$  versus  $I_C$**



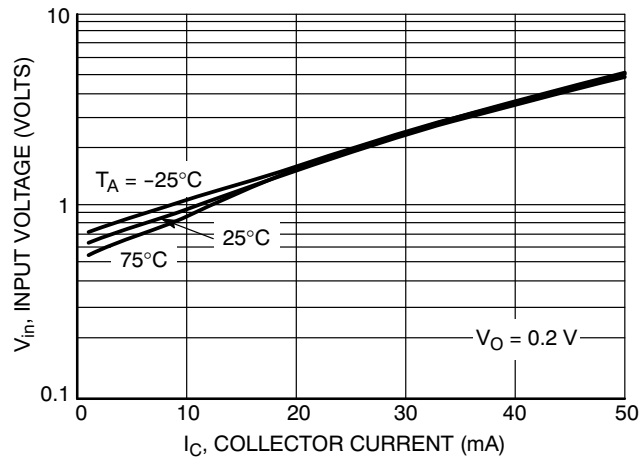
**Figure 28. DC Current Gain**



**Figure 29. Output Capacitance**



**Figure 30. Output Current versus Input Voltage**



**Figure 31. Input Voltage versus Output Current**

TYPICAL ELECTRICAL CHARACTERISTICS — MMUN2230LT1

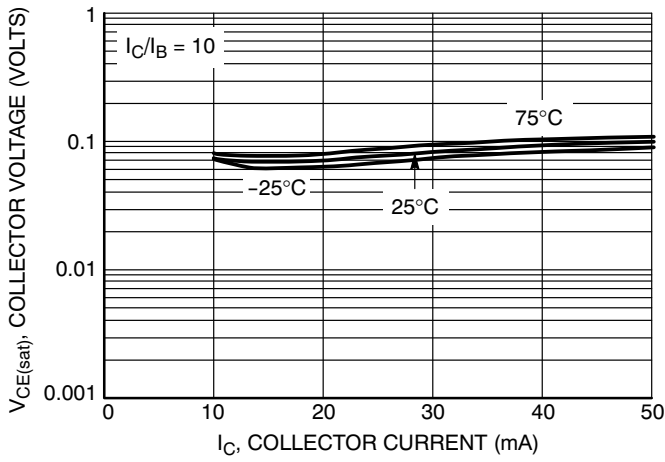


Figure 32.  $V_{CE(sat)}$  versus  $I_C$

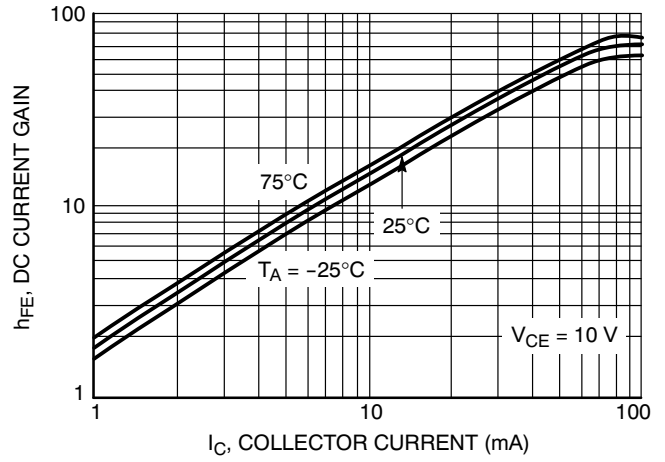


Figure 33. DC Current Gain

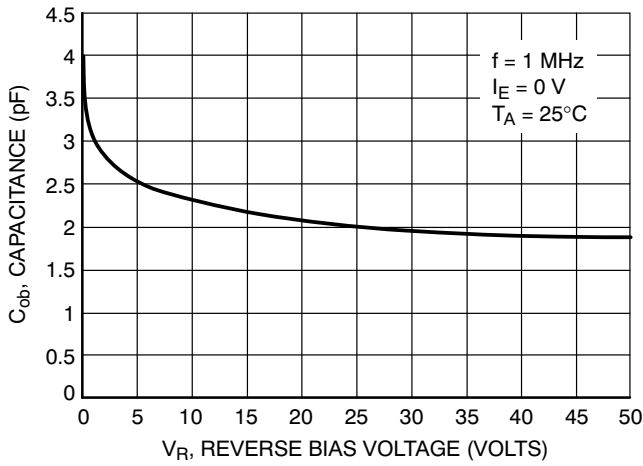


Figure 34. Output Capacitance

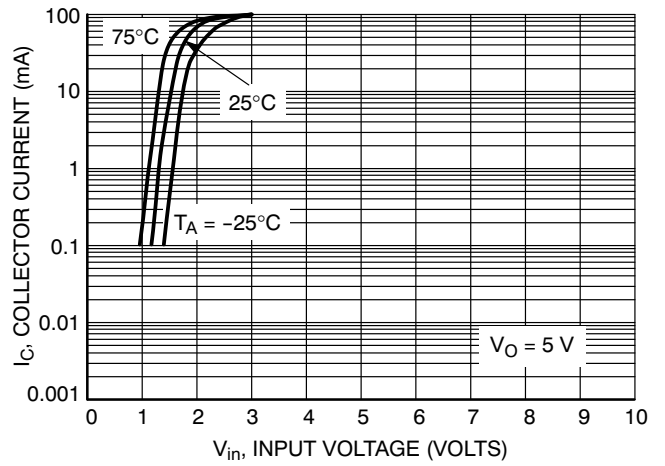


Figure 35. Output Current versus Input Voltage

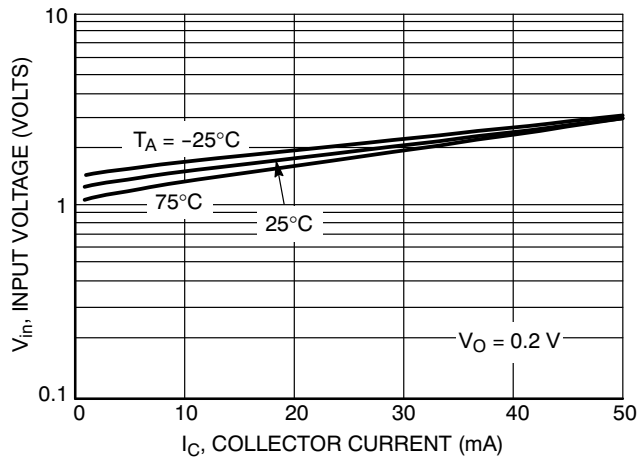
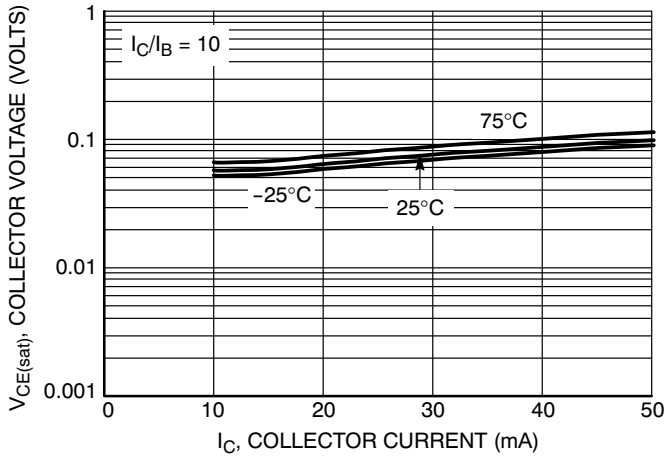


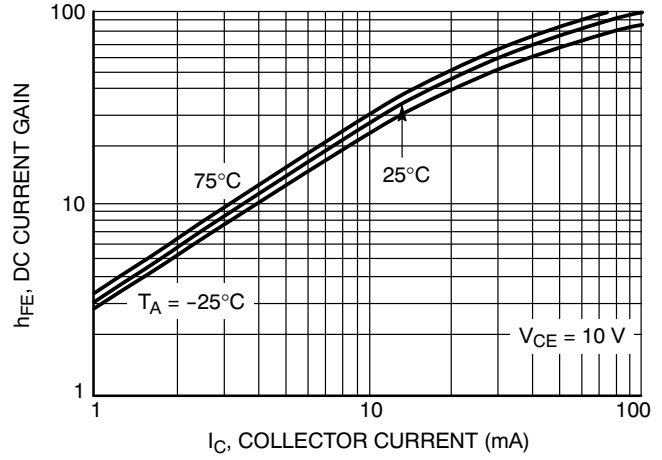
Figure 36. Input Voltage versus Output Current

# MMUN2211LT1 Series

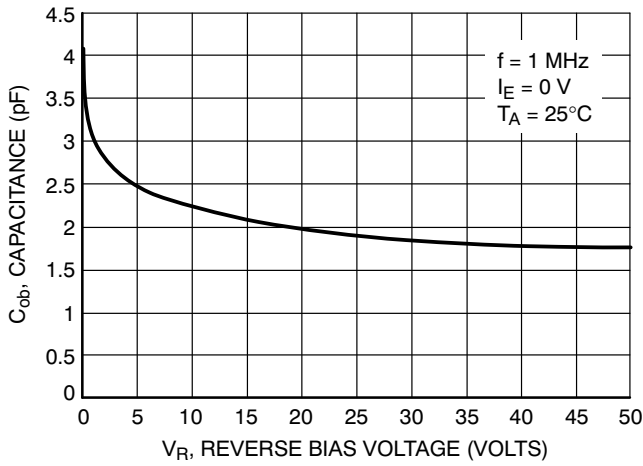
## TYPICAL ELECTRICAL CHARACTERISTICS — MMUN2231LT1



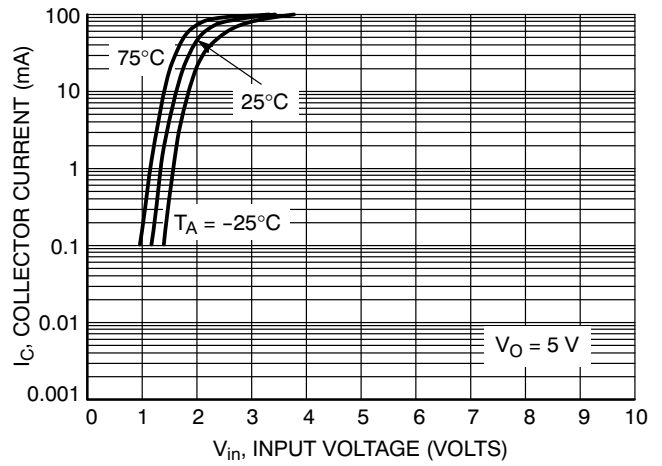
**Figure 37.  $V_{CE(sat)}$  versus  $I_C$**



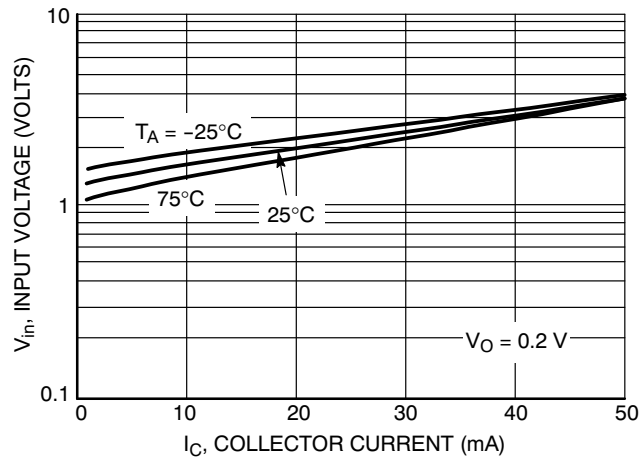
**Figure 38. DC Current Gain**



**Figure 39. Output Capacitance**



**Figure 40. Output Current versus Input Voltage**



**Figure 41. Input Voltage versus Output Current**

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MMUN2232LT1

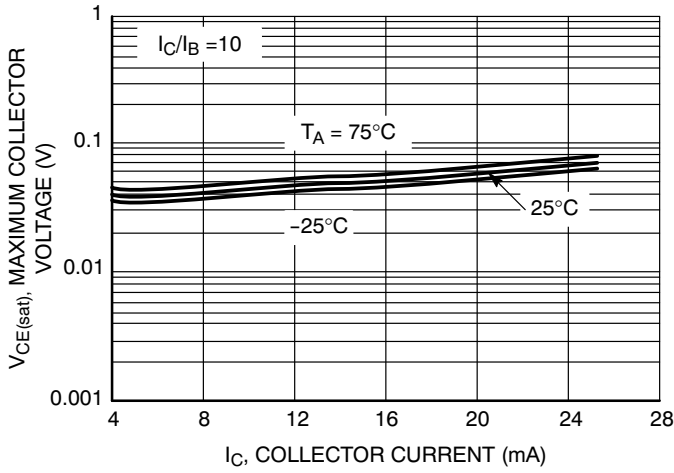


Figure 42.  $V_{CE(sat)}$  vs.  $I_C$

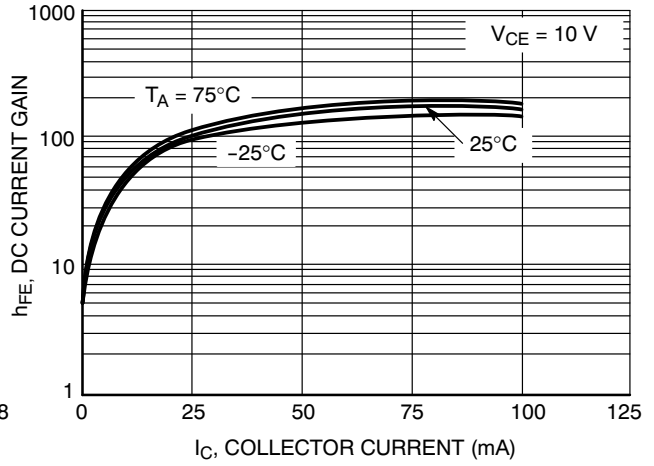


Figure 43. DC Current Gain

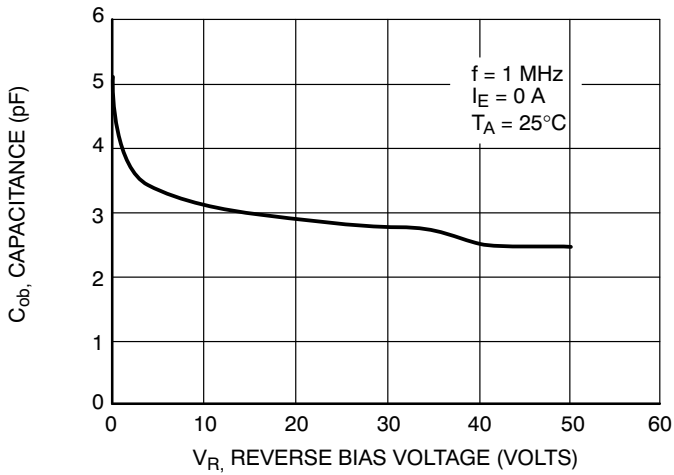


Figure 44. Output Capacitance

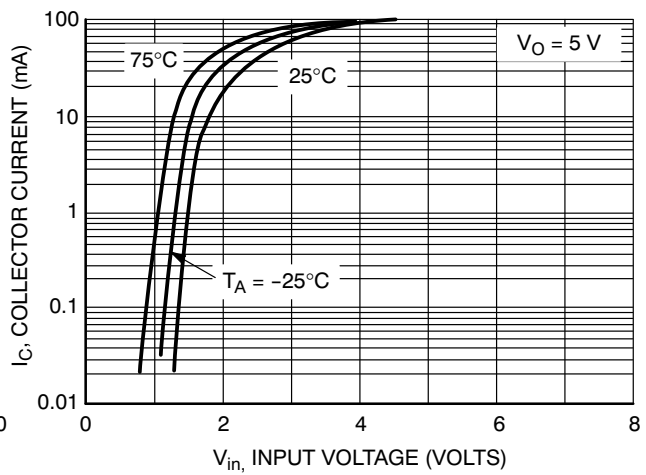


Figure 45. Output Current vs. Input Voltage

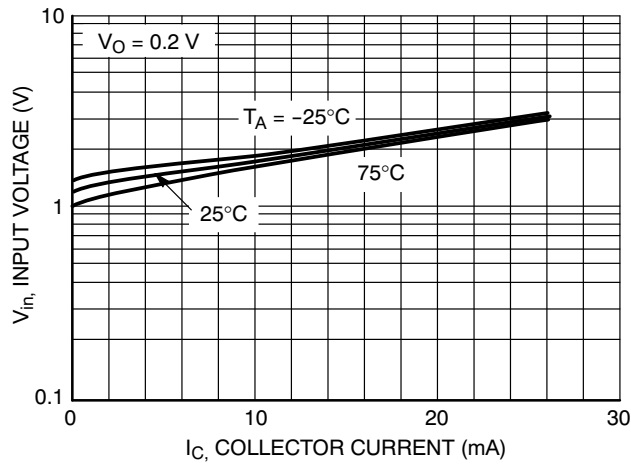


Figure 46. Output Voltage vs. Input Current

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MMUN2233LT1

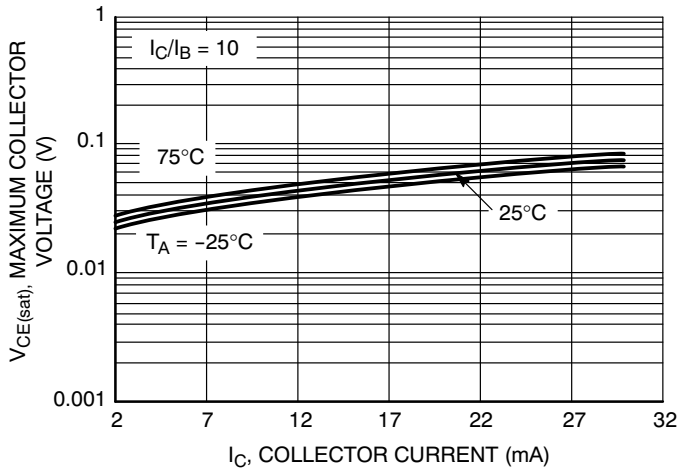


Figure 47.  $V_{CE(sat)}$  vs.  $I_C$

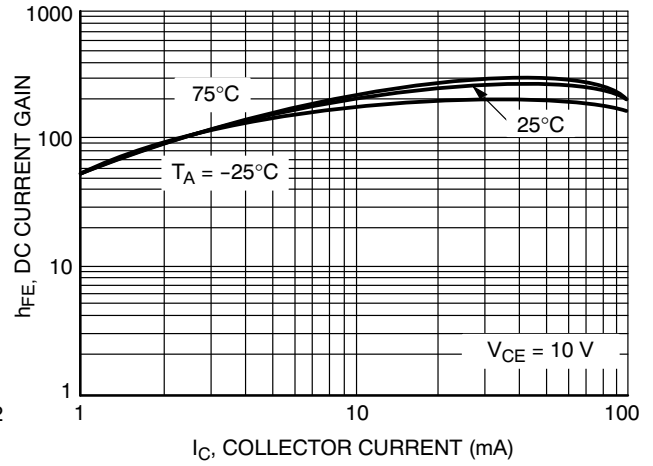


Figure 48. DC Current Gain

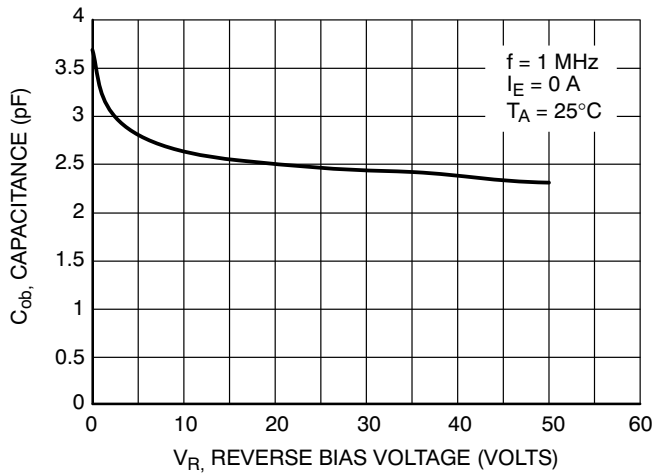


Figure 49. Output Capacitance

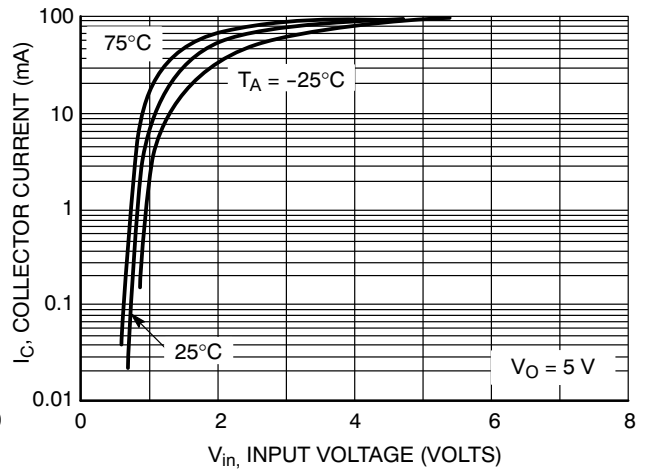


Figure 50. Output Current vs. Input Voltage

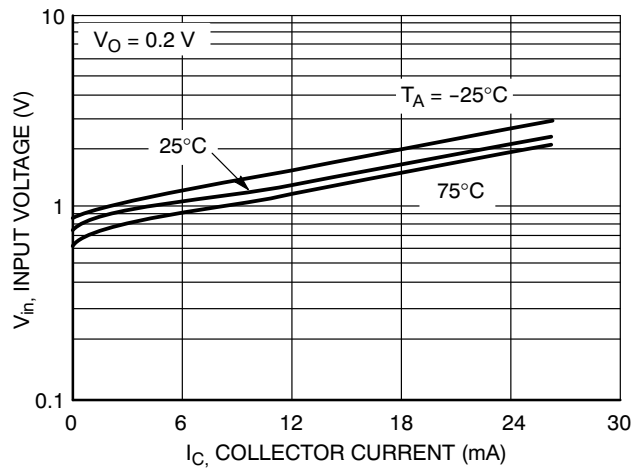


Figure 51. Input Voltage vs. Output Current

MMUN2211LT1 Series

TYPICAL ELECTRICAL CHARACTERISTICS — MMUN2234LT1

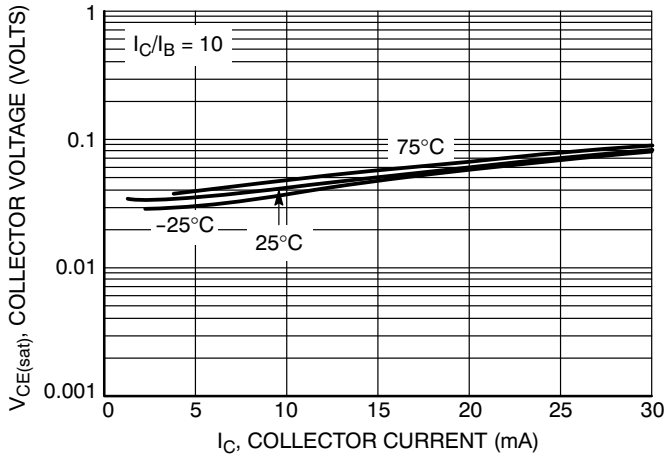


Figure 52.  $V_{CE(sat)}$  versus  $I_C$

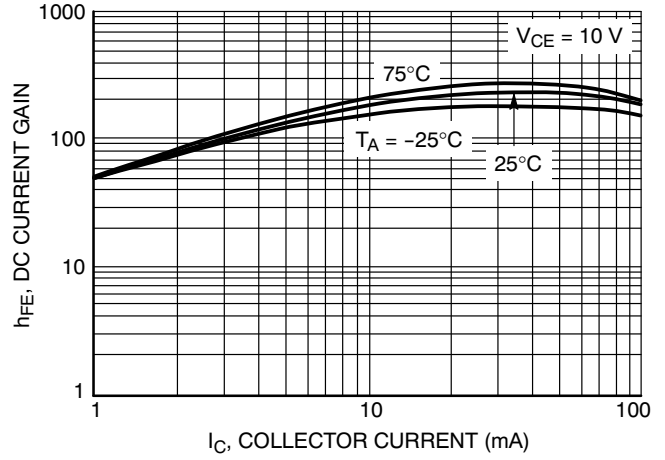


Figure 53. DC Current Gain

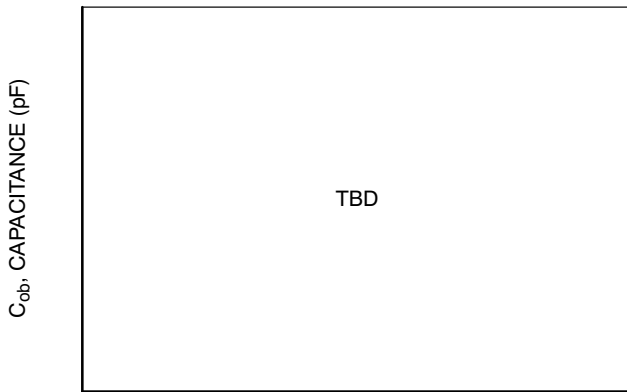


Figure 54. Output Capacitance

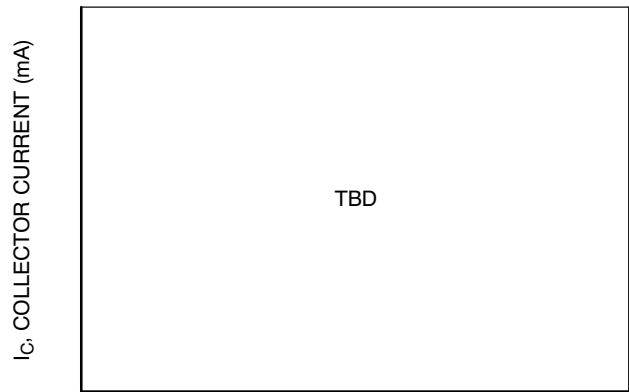


Figure 55. Output Current versus Input Voltage

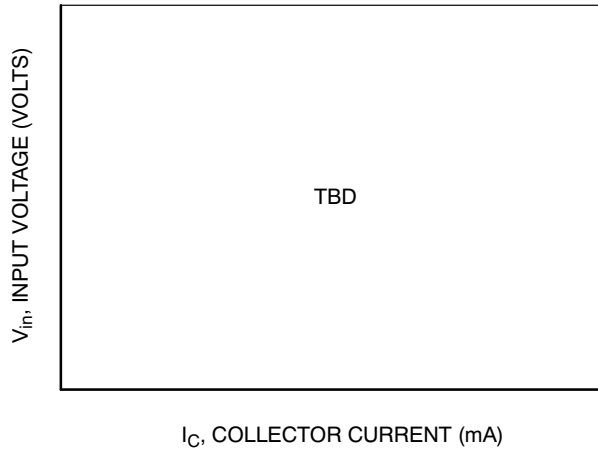


Figure 56. Input Voltage versus Output Current

# MMUN2211LT1 Series

## TYPICAL APPLICATIONS FOR NPN BRTs

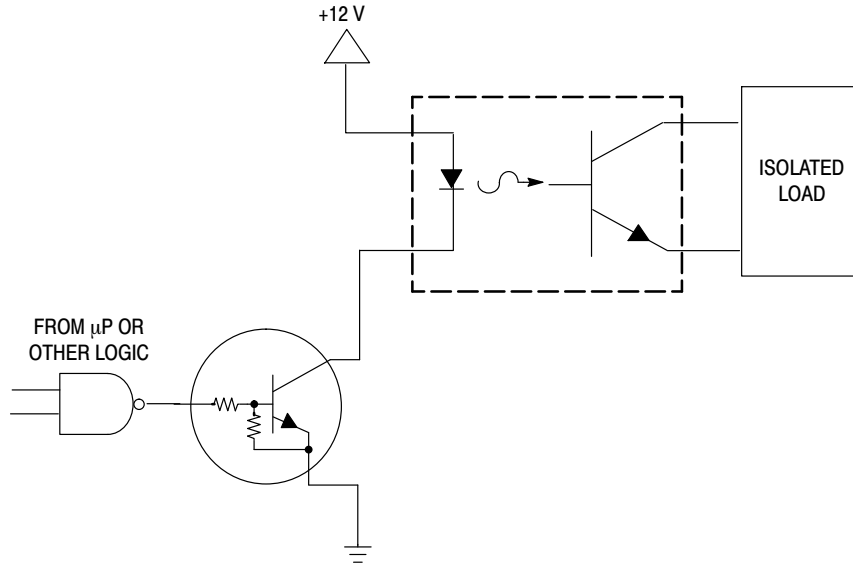


Figure 57. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

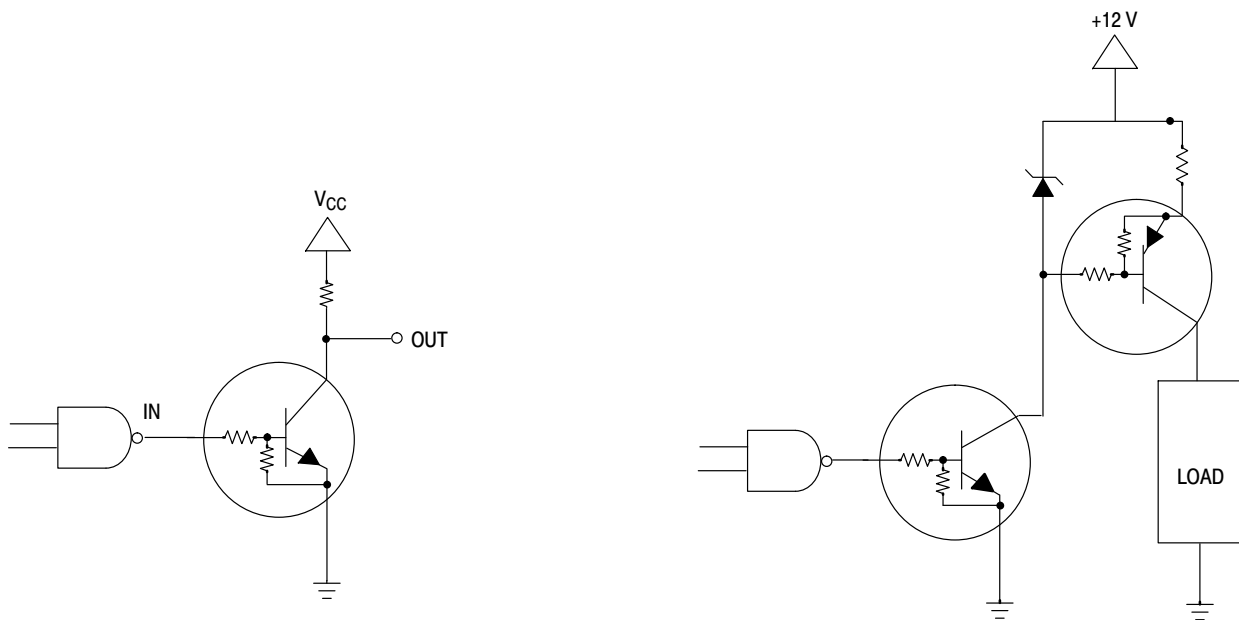


Figure 58. Open Collector Inverter: Inverts the Input Signal

Figure 59. Inexpensive, Unregulated Current Source

## MMUN2211LT1 Series

### ORDERING INFORMATION

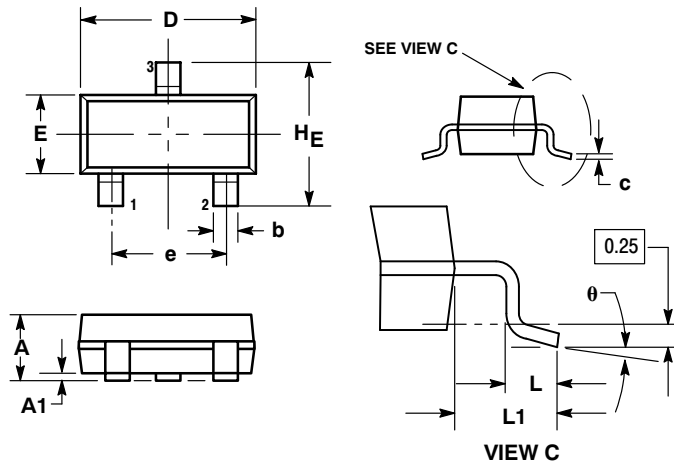
Device	Marking	R1(k)	R2(k)	Package	Shipping <sup>†</sup>
MMUN2211LT1	A8A	10	10	SOT-23	3000 / Tape & Reel
MMUN2211LT1G		10	10	SOT-23 (Pb-Free)	
MMUN2211LT3		10	10	SOT-23	10,000 / Tape & Reel
MMUN2211LT3G		10	10	SOT-23 (Pb-Free)	
MMUN2212LT1	A8B	22	22	SOT-23	3000 / Tape & Reel
MMUN2212LT1G		22	22	SOT-23 (Pb-Free)	
MMUN2213LT1	A8C	47	47	SOT-23	
MMUN2213LT1G		47	47	SOT-23 (Pb-Free)	
MMUN2214LT1	A8D	10	47	SOT-23	
MMUN2214LT1G		10	47	SOT-23 (Pb-Free)	
MMUN2215LT1	A8E	10	∞	SOT-23	
MMUN2215LT1G		10	∞	SOT-23 (Pb-Free)	
MMUN2216LT1	A8F	4.7	∞	SOT-23	
MMUN2216LT1G		4.7	∞	SOT-23 (Pb-Free)	
MMUN2230LT1	A8G	1.0	1.0	SOT-23	
MMUN2230LT1G		1.0	1.0	SOT-23 (Pb-Free)	
MMUN2231LT1	A8H	2.2	2.2	SOT-23	
MMUN2231LT1G		2.2	2.2	SOT-23 (Pb-Free)	
MMUN2232LT1	A8J	4.7	4.7	SOT-23	
MMUN2232LT1G		4.7	4.7	SOT-23 (Pb-Free)	
MMUN2233LT1	A8K	4.7	47	SOT-23	
MMUN2233LT1G		4.7	47	SOT-23 (Pb-Free)	
MMUN2234LT1	A8L	22	47	SOT-23	
MMUN2234LT1G		22	47	SOT-23 (Pb-Free)	
MMUN2234LT3		22	47	SOT-23	
MMUN2234LT3G		22	47	SOT-23 (Pb-Free)	
MMUN2238LT1	A8R	2.2	∞	SOT-23	
MMUN2238LT1G		2.2	∞	SOT-23 (Pb-Free)	
MMUN2241LT1	A8U	100	∞	SOT-23	
MMUN2241LT1G		100	∞	SOT-23 (Pb-Free)	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MMUN2211LT1 Series

## PACKAGE DIMENSIONS

SOT-23 (TO-236)  
CASE 318-08  
ISSUE AN



NOTES:

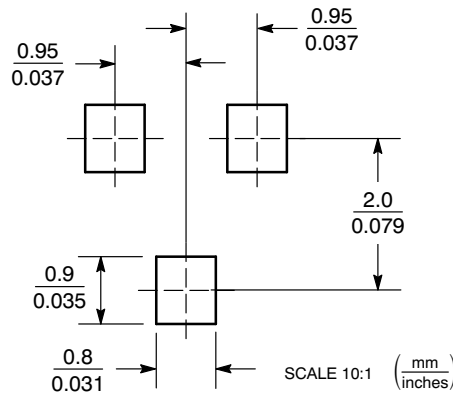
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104


STYLE 6:

- PIN 1. BASE
- EMITTER
- COLLECTOR

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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